L	Hits	Search Text	DB	Time stamp
Number 1	2	6108191.pn.	USPAT;	2001/08/20
_		-	US-PGPUB;	17:18
			EPO; JPO;	
			DERWENT;	
2	1	US-6108191-A.DID.	DERWENT	2001/08/20
_				16:38
3	3	3210607.pn.	USPAT;	2001/08/20
			US-PGPUB; EPO; JPO;	17:18
			DERWENT;	
			IBM TDB	
-	18	two adj different adj dielectric and	USPAT;	2001/08/16
		capacitor and (257/\$ 438/\$)	US-PGPUB; EPO; JPO;	17:38
			DERWENT;	
			IBM TDB	
-	8	("3210607" "4219866" "5036424"	USPAT	2001/08/16
		"5036425" "5117326" "5561587" "5668694" "5905049").PN.		17:20
_	o	6108191.URPN.	USPAT	2001/08/16
				17:20
-	0	6108191.URPN.	USPAT	2001/08/16
_	2	6136725.pn.	USPAT;	17:21 2001/08/16
_		0130723.pii.	US-PGPUB;	17:22
			EPO; JPO;	
			DERWENT;	,
_	0	6136725.URPN.	IBM TDB USPAT	2001/08/16
_		0130723.0KLW.	002.11	17:22
-	1	US-6136725-A.DID.	DERWENT	2001/08/16
	2	6100101 nn	USPAT;	17:22 2001/08/16
-	2	6108191.pn.	US-PGPUB;	17:24
			EPO; JPO;	
			DERWENT;	
_	o	6108191.URPN.	IBM TDB USPAT	2001/08/16
		01001511011111		17:23
-	1	US-6108191-A.DID.	DERWENT	2001/08/16
	1	 de-4300808-\$.did.	USPAT;	17:23 2001/08/16
-	1	uc 3500000 y.u.u.	US-PGPUB;	17:25
			EPO; JPO;	
			DERWENT;	
_	7	ep-298811-\$.did. ep-617440-\$.did.	IBM TDB USPAT;	2001/08/16
	'	ep-664548-\$.did. de-3442790-\$.did.	US-PGPUB;	17:28
		de-4300808-\$.did.	EPO; JPO;	
			DERWENT;	
_	259	(different combination) adj dielectric	USPAT;	2001/08/16
		and capacitor and (257/\$ 438/\$)	US-PGPUB;	20:19
			EPO; JPO;	
			DERWENT; IBM TDB	
_	66	((different combination) adj dielectric	USPAT;	2001/08/16
		and capacitor and (257/\$ 438/\$)) and	US-PGPUB;	20:21
		(tantalum adj oxide "Ta.sub.20.sub.5"	EPO; JPO;	
		"Ta.sub.2 O.sub.5" tantalum adj pentoxide)	DERWENT; IBM TDB	
-	188	different adj dielectric and capacitor	USPAT;	2001/08/16
		and (257/\$ 438/\$)	US-PGPUB;	20:20
	i		EPO; JPO;	
	1		DERWENT;	

-	51	(different adj dielectric and capacitor and (257/\$ 438/\$)) and (tantalum adj oxide "Ta.sub.20.sub.5" "Ta.sub.2 O.sub.5" tantalum adj pentoxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2001/08/17 00:02
-	51	crystalline adj structure with (silicon adj nitride "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" "Si.sub.3N.sub.4" SiN)	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2001/08/16
-	3393	nitride silicon adj oxide titanium adj oxide titanium adj dioxide alumina aluminum adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "Si0.sub.2" "Si O.sub.2" "Ti0.sub.2" "Ti O.sub.2"	IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 23:58
-	462	"Al.sub.20.sub.3" "Al.sub.2 0.sub.3") (amorphous adj (dielectric silicon adj nitride silicon adj oxide titanium adj oxide titanium adj dioxide alumina aluminum adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "Si0.sub.2" "Si 0.sub.2" "Ti0.sub.2" "Ti 0.sub.2" "Al.sub.20.sub.3" "Al.sub.2 0.sub.3"))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:55
-	107	and (257/\$ 438/\$) ((amorphous adj (dielectric silicon adj nitride silicon adj oxide titanium adj oxide titanium adj oxide titanium adj oxide alumina aluminum adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "Si0.sub.2" "Si O.sub.2" "Ti0.sub.2" "Ti O.sub.2" "Al.sub.20.sub.3" "Al.sub.2 O.sub.3")) and (257/\$ 438/\$)) and capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:56
-	23	((amorphous adj (dielectric silicon adj nitride silicon adj oxide titanium adj oxide titanium adj oxide titanium adj oxide titanium adj oxide "Si.sub.3.N.sub.4" "Si.sub.3 N.sub.4" "Si0.sub.2" "Si O.sub.2" "Ti0.sub.2" "Ti O.sub.2" "Al.sub.20.sub.3" "Al.sub.2 O.sub.3")) and (257/\$ 438/\$)) and capacitor.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 22:56
	1236	barium adj strontium adj titanate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/16 23:58
_	478	(barium adj strontium adj titanate) and capacitor and (361/\$ 257/\$ 438/\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/08/17